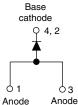


Vishay High Power Products

Surface Mountable Input Rectifier Diode, 8 A





PRODUCT SUMMARY				
V _F at 5 A 1 V				
I _{FSM}	200 A			
V _{RRM}	800/1200 V			

DESCRIPTION/FEATURES

The 8EWS..SPbF rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

The **high reverse voltage** range available allows design of input stage primary rectification with **outstanding voltage surge** capability.

Typical applications are in input rectification and these products are designed to be used with Vishay HPP switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level.

Compliant to RoHS directive 2002/95/EC.

OUTPUT CURRENT IN TYPICAL APPLICATIONS							
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS				
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 $\mu m)$ copper	1.2	1.6					
Aluminum IMS, R _{thCA} = 15 °C/W	2.5	2.8	A				
Aluminum IMS with heatsink, $R_{thCA} = 5 \text{ °C/W}$	5.5	6.5					

Note

• $T_A = 55 \ ^{\circ}C$, $T_J = 125 \ ^{\circ}C$, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES						
I _{F(AV)}	Sinusoidal waveform	8	А					
V _{RRM}		800/1200	V					
I _{FSM}		200	А					
V _F	8 A, T _J = 25 °C	1.10	V					
TJ		- 55 to 150	°C					

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA					
8EWS08SPbF	800	900	0.5					
8EWS12SPbF	1200	1300	0.5					

8EWS..SPbF High Voltage Series



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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	DL TEST CONDITIONS		UNITS	
Maximum average forward current	I _{F(AV)}	T_C = 105 °C, 180° conduction half sine wave	8		
Maximum peak one cycle		10 ms sine pulse, rated V_{RRM} applied	170	А	
non-repetitive surge current	10 ms sine pulse, no voltage reapplied	200			
Manimum 12t fau fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied	130	A ² s	
Maximum I ² t for fusing I ² t		10 ms sine pulse, no voltage reapplied	145	A-5	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied 1450		A²√s	

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum forward voltage drop	V _{FM}	8 A, T _J = 25 °C		1.1	V	
Forward slope resistance	r _t	T 150 %		20	mΩ	
Threshold voltage	V _{F(TO)}	T _J = 150 °C	0.82	V		
Maximum reverse leakage current		T _J = 25 °C	V _B = Rated V _{BBM}	0.05	mA	
Maximum reverse leakage current		$T_J = 150 \text{ °C}$		0.50		

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 150	°C	
Soldering temperature	Ts		240		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C MI	
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		62	°C/W	
Approximate weight			1	g	
Approximate weight			0.03	oz.	
Marking device		Case style D-PAK (TO-252AA)	8EW	S12S	

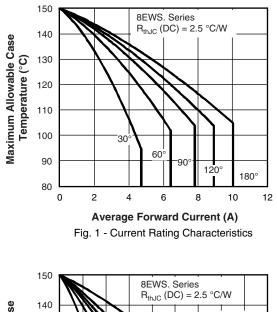
Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994



8EWS..SPbF High Voltage Series

Surface Mountable Vishay High Power Products Input Rectifier Diode, 8 A



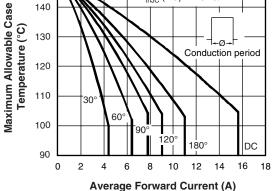
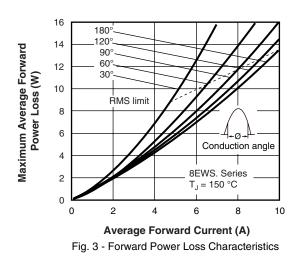
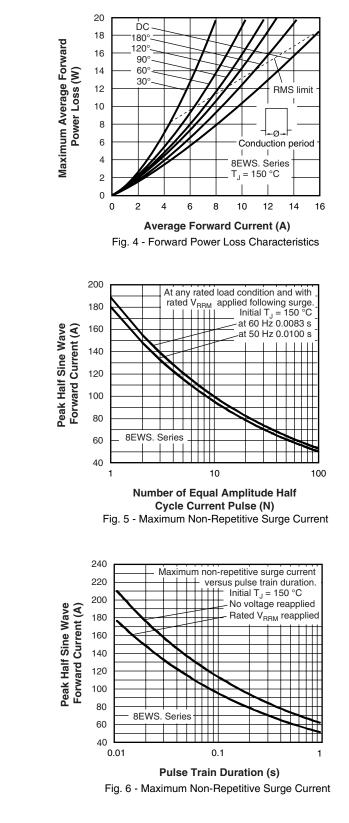


Fig. 2 - Current Rating Characteristics





8EWS..SPbF High Voltage Series

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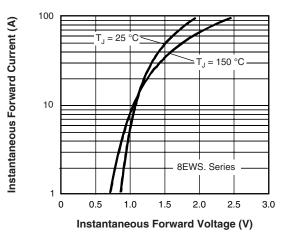


Fig. 7 - Forward Voltage Drop Characteristics

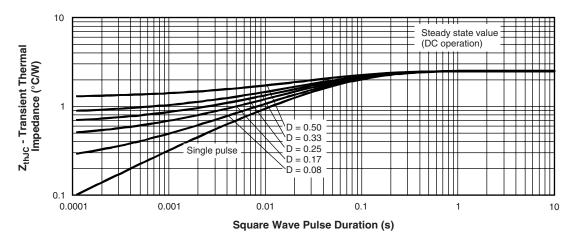


Fig. 8 - Thermal Impedance ZthJC Characteristics



Surface Mountable Vishay High Power Products Input Rectifier Diode, 8 A

ORDERING INFORMATION TABLE

Device code	8	E	w	S	12	S	TR	PbF
	1	2	3	4	5	6	7	8
	1 - 2 - 3 - 4 -	· Circ E = · Pac W =						
	5 - 6 - 7 -	 Volt S = • TF • TF • TF 	S = Standard recovery rectifier Voltage ratings S = Surface mountable • TR = Tape and reel • TRR = Tape and reel (right oriented) • TRL = Tape and reel (left oriented) PbF = Lead (Pb)-free					

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95016				
Part marking information	www.vishay.com/doc?95059			
Packaging information	www.vishay.com/doc?95033			



Vishay

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